## NSN 5961-00-082-3737

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View Online at https://aerobasegroup.com/nsn/5961-00-082-3737 **Inclosure Material:** Metal **Overall Length:** 0.562 inches **Overall Height:** 0.562 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 55.0 collector to emitter voltage/static/base open and 100.0 collector to emitter voltage, dc with specified circuit between base and emitter **Current Rating Per Characteristic:** Between 3.00 amperes source cutoff current and 6.00 amperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 210.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 81349-mil-s-19500/208 government specification Shelf Life: N/a

Fiig:

No

**Unit Of Measure:** 

Demilitarization: